

Data sheet acquired from Harris Semiconductor

# **CMOS Presettable Up/Down Counters** (Dual Clock With Reset)

High-Voltage Types (20-Volt Rating) CD40192 - BCD Type CD40193 - Binary Type

■ CD40192B Presettable BCD Up/ Down Counter and the CD40193B Presettable Binary Up/Down Counter each consist of 4 synchronously clocked, gated "D" type flip-flops connected as a counter. The inputs consist of 4 individual jam lines, a PRESET ENABLE control, individual CLOCK UP and CLOCK DOWN signals and a master RE-SET. Four buffered Q signal outputs as well as CARRY and BORROW outputs for multiple-stage counting schemes are provided.

The counter is cleared so that all outputs are in a low state by a high on the RE-SET line. A RESET is accomplished asynchronously with the clock. Each output is individually programmable asynchronously with the clock to the level on the corresponding jam input when the PRESET ENABLE control is low.

The counter counts up one count on the positive clock edge of the CLOCK UP signal provided the CLOCK DOWN line is high. The counter counts down one count on the positive clock edge of the CLOCK DOWN signal provided the CLOCK UP line is high.

The CARRY and BORROW signals are high when the counter is counting up or down. The CARRY signal goes low one-half clock cycle after the counter reaches its maximum count in the count-up mode. The BORROW signal goes low one-half clock cycle after the counter reaches its minimum count in the count-down mode. Cascading of multiple packages is easily accomplished without the need for additional external circuitry by tying the BORROW and CARRY outputs to the CLOCK DOWN and CLOCK UP inputs, respectively, of the succeeding counter

The CD40192B and CD40193B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

# CD40192B, CD40193B Types

#### Features:

- Individual clock lines for counting up or counting down
- Synchronous high-speed carry and borrow propagation delays for cascading
- Asynchronous reset and preset capability
- Medium-speed operation—f<sub>CL</sub> = 8 MHz (typ.) @ 10 V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin over full package temperature

1 V at V<sub>DD</sub> = 5 V 2 V at V<sub>DD</sub> = 10 V 2.5 V at V<sub>DD</sub> = 15 V

Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

### 92CS-27561RI 92 15 CLOCK DOWN -WASSON -CLOCK UP . - CARRY PRESET ENABLE Q3 VSS

CD40192B, CD40193B

**FUNCTIONAL DIAGRAM** 

PRESET

CLOCK UP

RESET

CLOCK DOWN

#### 9205-2756482

02

04

13 BORROW

CARRY

V<sub>DD</sub> • 16

CD40192B, CD40193B TERMINAL ASSIGNMENT

## Applications:

- Up/down difference counting
- Multistage ripple counting
- Synchronous frequency dividers
- A/D and D/A conversion
- Programmable binary or BCD counting

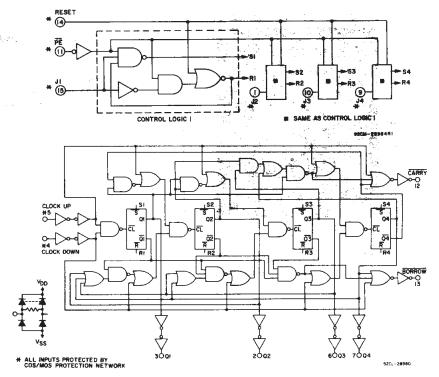


Fig. 1 - CD401928 logic diagram (BCD).

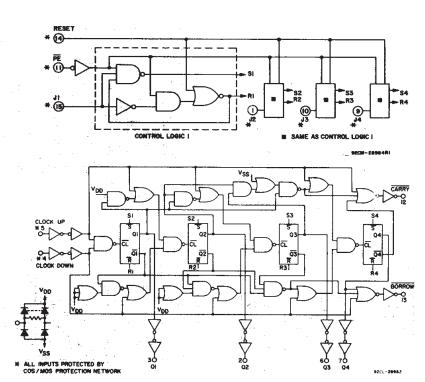


Fig. 2 — CD40193B logic diagram (binary).

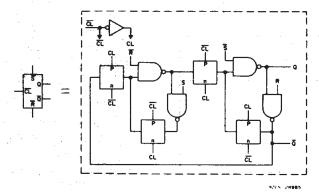


Fig. 4 — Internal logic of Flip-flop.

#### TRUTH TABLE

CLOC		CLOCK DOWN	PRESET ENABLE	RESET	ACTION
	197	1 1	1	0	COUNT UP
<b>N</b>		1	1	0	NO COUNT
1			1	0	COUNT DOWN
1		~_	1	0	NO COUNT
×		X	0	0	PRESET
×		Х	X	1	RESET

1 = HIGH LEVEL

0 = LOW LEVEL

X = DON'T CARE

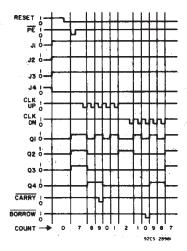


Fig. 3 - CD40192B timing diagram.

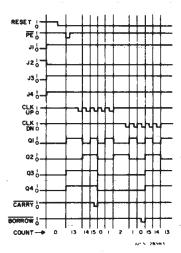


Fig. 5 — CD40193B timing diagram.

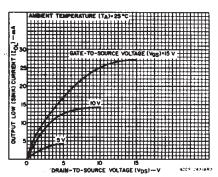


Fig. 6 — Typical output low (sink) current characteristics.

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to VSS Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to VDD +0.5V
DC INPUT CURRENT, ANY ONE INPUT±10mA
POWER DISSIDATION REP PACKAGE (Po)-
For TA = -55°C to +100°C
For T <sub>A</sub> = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (TA)55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPÉRATURE (DURING SOLDÉRING):
At distance $1/16 \pm 1/32$ inch $(1.59 \pm 0.79$ mm) from case for 10s max +265°C

## RECOMMENDED OPERATING CONDITIONS at T<sub>A</sub> = 25°C (unless otherwise specified)

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	V <sub>DD</sub>	LIM	UNITS		
	(V)	Min.	Max.	1	
Supply Voltage Range (For T <sub>A</sub> = Full Temp. Range)	T -	3	18	٧	
Barrary Times	5	80	: -		
RESET or PE		40	-	กร	
RESEI OFFE	15	30		ी र ५६०	
Pulse Width:	5	480	_		
RESET	10	300		ns	
NESE!	15	260			
	5	240	_		
PE STATE OF THE ST	10	170	<u> </u>	ns	
	15	140	_		
	5	180	_		
CLOCK	10	90		ns	
	15	60	, <del></del> .	l .	
A	5		2		
Clock Input Frequency	10	DC	4	MHz	
et ser	15	l	5.5		
* .	5	- :	15		
Clock Rise & Fall Time	10	_	15	μs	
The State of the S	15	_	5		

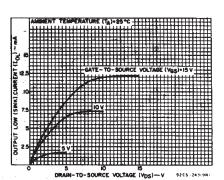


Fig. 7 — Minimum output low (sink) current characteristics.

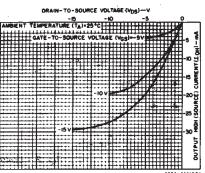


Fig. 8 — Typical output high (source) \*\*\*cs\*\*
current characteristics.

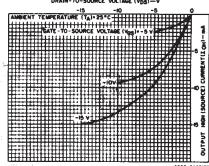


Fig. 9 — Minimum output high (source) \*\*cs-14326 current characteristics.

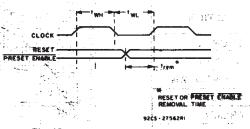


Fig. 10 — Timing diagram defining t<sub>rem</sub>.

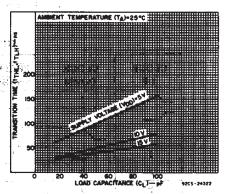


Fig. 11 — Typical transition time as a function of load capacitance.

#### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)								
ISTIC	Vo	VIN (V)	V <sub>DD</sub> (V)					+25			UNITS	
-	. (V)			-55	-40	+85	+125	Min.	Typ.	Max.		
Quiescent Device Current, IDD Max.	_	0,5	5	5	5	150	150	_	0.04	5	μΑ	
	-	0,10	10	10	10	300	300		0.04	10		
	-	0,15	15	20	20	600	600	-	0.04	20		
	-	0,20	20	100	100	3000	3000	-	0.08	100	1	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	·	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34.	6.8	-		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mΑ	
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1,15	-1.6	-3.2	-		
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-		
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-		
Output Voltage:	_	0,5	5	0.05			-	0	0.05	V		
Low-Level, VOL Max.	-	0,10	10	0.05			_	0	0.05			
AOF Max.		0,15	15	0.05			. =	0	0.05			
Output Voltage:		0,5	5		4	95		4.95	5	-	<b>.V</b>	
High-Level,	-	0,10	10	9.95 9.95 10 14.95 14.95 15			-					
VOH Min.	-	0,15	15				-					
Input Low	0.5, 4.5	. –	5		1	.5				1.5	-	
Voltage,	1, 9	-	10	3			-		3			
VIL Max.	1.5,13.5	_	15	4			-	_	4	١		
Input High	0.5, 4.5		5		- 3	3.5		3.5		-	V	
Voltage, VIH Min.	1, 9		.10	7			7		_			
	1,5,13.5	_	15			11		11	-	_		
Input Current	-	0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μА	

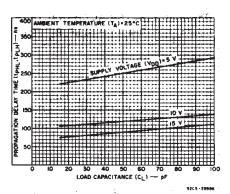


Fig. 12 — Typical propagation delay time as a function of load capacitance.

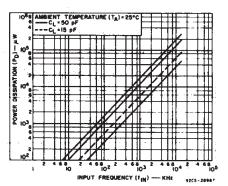
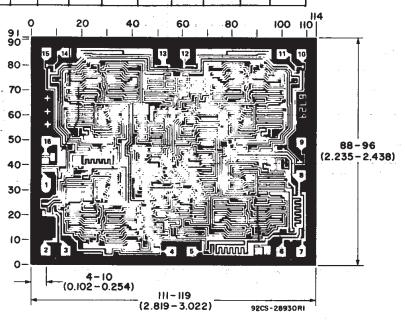


Fig. 13 - Dynamic power dissipation.



Dimensions and pad layout for the CD401928H (dimensions and pad layout for the CD401938H are identical).

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3} \, \text{inch})$ .

# DYNAMIC ELECTRICAL CHARACTERISTICS at T $_A$ = 25°C Input t $_r$ , t $_f$ = 20 ns, C $_L$ = 50 pF, R $_L$ = 200 k $\Omega$

CHARACTERISTIC	V <sub>DD</sub>		UNITS		
	(V)	Min.	Тур.	Max.	
Propagation Delay Time tpHL, tpLH:	5	-	250	500	
CLOCK UP or CLOCK DOWN to Q, RESET to Q	10	-	120	240	ns
	15	_	90	180	
PE to Q	5	-	200	400	
PE to U	10	-	100 70	200	пs
		_	-	140	
CLOCK UP to CARRY, CLOCK DOWN to BORROW	10	-	160 80	320 160	
CEGOR OF TO CARRY, CEGOR DOWN TO BOTTHOW	15	_	60	120	ns
	5	-	300	600	
RESET or PE to BORROW or CARRY	10	_	150	300	ns
	15	_	110	220	''"
	5	_	100	200	
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>	10		50	100	ns
	15 -		40	80	
	5	_	40	80	
Min. Removal Time, t <sub>rem</sub> * RESET or PE	10	-	20	40	ns
	15		15	30	
	5	–	240	480	
Min. Pulse Width, tw RESET	10		150	300	ns
	15	-	130	260	<u> </u>
PE	5		120	240	
PE PE	10	-	85	170	ns
· · · · · · · · · · · · · · · · · · ·	15		70	140	
CLOCK	10		90 45	180 90	
020011	15	_	30	60	ns
	5	2	4	<u> </u>	
Max. Clock Input Frequency, fCI	10	4	8		MHz
	15	5.5	11	<b>.</b>	
* * * * * * * * * * * * * * * * * * * *	5	_	-	15	1.1
Clock Rise & Fall Time, t <sub>r</sub> , t <sub>f</sub>	10		. –	15	μs
Average Communication (Communication Communication Communi	15	_	_	5	
Input Capacitance, C <sub>IN</sub> :					
RESET		- :	10	15	pF
All Other Inputs			5	7.5	рF

<sup>\*</sup> The time required for RESET or PRESET ENABLE control to be removed before clocking (see timing diagram, Fig. 10.

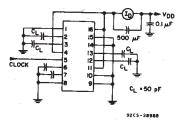


Fig. 14 - Dynamic power dissipation test circuit.

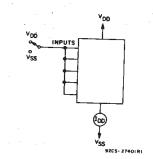


Fig. 15 - Quiescent-device-current test circuit.

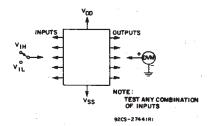


Fig. 16 - Input-voltage test circuit.

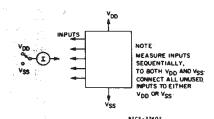


Fig. 17 - Input current test circuit.

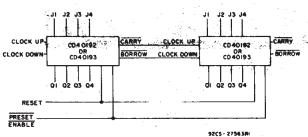


Fig. 18 - Cascaded counter packages.

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